



33Features:

- MEMS Technology
- Small SMD package: 2.0 x 1.2 mm (2012)
- Fixed 32.768 kHz output frequency
- NanoDrve[™] programmable output swing for lowest power
- Pb-free, RoHS and REACH compliant





Typical Applications:

- Mobile Phones
- Tablets
- Health and Wellness Monitors
- Wireless Keypads
- Ultra-Small Notebook PC

Electronic Specifications:						
Fixed Output Frequency	32.768 kHz					
Frequency Tolerance ^[1]	±20 ppm max	T _A = +25°C, Post Reflow, Vdd: 1.5V – 3.63V				
	±75 ppm max	$T_A = -10^{\circ}C \text{ to } +70^{\circ}C \text{ Vdd: } +1.50V \text{ to } +3.63V$				
Frequency Stability ^[2]	±100 ppm max	$T_A = -40^{\circ}C$ to +85°C, Vdd: +1.50V to +3.63V				
	±250 ppm max	T _A = -10°C to +70°C, Vdd: +1.20V to+1.50V				
Aging +25°C ±2°C	±1 ppm max	1 st Year				
Operational Supply Voltage	+1.20V min, +3.63 V max +1.50V min, +3.63 V max	$T_A = -10^{\circ}C \text{ to } +70^{\circ}C$ $T_A = -40^{\circ}C \text{ to } +85^{\circ}C$				
Core Operating Current ^[3]	0.90 μA typ. 1.30 μA max 1.40 μA max	T_A - +25°C, Vdd: +1.80V No load T_A = -10°C to +70°C, Vdd max, +3.63V No load T_A = -40°C to +85°C, Vdd max, +3.63V No load				
Output Stage Operating Current ^[3]	0.065 μΑ/Vpp typ. 0.125 μΑ/Vpp max	$T_A = -40^{\circ}C$ to +85°C, Vdd: 1.5V – 3.63V. No load				
Power-Supply Ramp	100 mSec max	$T_A = -40^{\circ}C$ to +85°C, 0 to 90% Vdd				
Start-up Time at Power-up ^[4]	180 mSec typ., 300 ms max 450 mSec max	$T_A = -40^{\circ}C \le T_A \le +50^{\circ}C$, valid output $T_A = +50^{\circ}C < T_A \le +85^{\circ}C$, valid output				

Notes:

1. Measured peak-to-peak. Tested with Agilent 53132A frequency counter. Due to the low operating frequency, the gate time must be ≥100 ms to ensure an accurate frequency measurement.

Stability is specified for two operating voltage ranges. Stability progressively degrades with supply voltage below 1.5V. Measured peak-to-peak. Inclusive of Initial Tolerance at 25°C, and variations over operating temperature, rated power supply voltage and load.
 Core operating current does not include output driver operating current or load current. To derive total operating current (no load), add core operating current + (0.065 µA/V) * (peak-to-peak output Voltage swing).

4.Measured from the time Vdd reaches 1.5V.

LVCMOS Output Option, $T_A = -40^{\circ}$ C to $+85^{\circ}$ C,, typical values are at $T_A = +25^{\circ}$ C						
Output Rise / Fall Time	100 nSec typ. 200 nSec max 50 nSec max	10-90% (Vdd), 15 pF load, Vdd = 1.5V to 3.63V 10-90% (Vdd), 5 pF load, Vdd ≥ 1.62V				
Symmetry	48/52% min/max					
Logic "1"	90% min	Vdd: 1.5V – 3.63V. IOH = -10 μA, 15 pF				
Logic '0"	10% max	Vdd: 1.5V – 3.63V. IOH = -10 µA, 15 pF				
N	anoDrive [™] Programmable, R	educed Swing Output				
Output Rise / Fall Time	200 nSec max	30-70% (VOL/VOH), 10 pF Load				
Symmetry	48/52% min/max					
AC-coupled Programmable Output Swing	0.20 V to 0.80 V typ.	Vdd: $1.5V - 3.63V$, 10 pF Load, I _{OH} / I _{OL} = ±0.2 µA. IM890 does not internally AC-couple. This output description is intended for a receiver that is AC-coupled. See Table 2 for acceptable NanoDrive swing options.				
DC-Biased Programmable Output Voltage High Range	0.60 V to 1.225 V typ.	Vdd: 1.5V – 3.63V. IOH = -0.2 µA, 10 pF Load. See Table 1 for acceptable VOH/VOL setting levels				
DC-Biased Programmable Output Voltage High Range	0.35 V to 0.80 V typ.	Vdd: $1.5V - 3.63V$. IOL = 0.2 μ A, 10 pF Load. See Table 1 for acceptable VOH/VOL setting levels.				
Programmable Output Voltage Swing Tolerance	±0.055 V max	TA = -40°C to +85°C, Vdd = 1.5V to 3.63V.				
Period Jitter	35 nSec _{RMS} typ.	Cycles = 10,000, T _A = 25°C, Vdd = 1.5V – 3.63V				







Ordering Information:

Part number Guide							
Package	ge Temp Range/ Freq Stability In ppm		Temp Range/ Coupled DC- coupled Output Voh Freq Stability In ppm Table 4		DC- coupled Output V _{ol} Or AC Swing Table 3		
	С	±75 (-10°C to +70°C)	A = AC Coupled	6 = 600 mV	1 = 200 mV (AC-coupled only)		
	1	±100 (-40°C to +85°C)	D = DC Coupled	7 = 700 mV	2 = 250 mV (AC-coupled only)		
				8 = 800 mV	3 = 350 mV		
				9 = 900 mV	4 = 400 mV		
IM890				0 = 1.00 V	5 = 500 mV		
				1 = 1.10 V	6 = 600 mV		
				2 = 1.225 V	7 = 700 mV		
				A = AC- coupled	8 = 800 mV		
				C = rail-to rail LVCMOS	C = rail-to rail LVCMOS		

Note:

1) Industrial temp & corresponding 100 ppm frequency stability. Note, 100 ppm is only available for the industrial temp range, and 75 ppm is only available for the commercial temp range.

Example 1:

Park Number: IM890-CDCC-32.768					
Package	IM890	ILSI Part Number			
Temp Range/ Freq Stabitlity in ppm	С	Temperature Range = -10°C to +70°C Frequency Stability = ±75 ppm			
Coupled	D	DC Coupled			
DC-coupled Output (V _{oh})	С	rail-to rail LVCMOS			
DC-coupled Output (V_{oh}) or AC Swing	С	rail-to rail LVCMOS			
32.768k	Frequency Output				

<u>Example 2</u>:

Park Number: IM890-IDCC-32.768						
Package	IM890	ILSI Part Number				
Temp Range/ Freq Stabitlity in ppm	I	Temperature Range = -40°C to +85°C Freguency Stability = ±100 ppm				
Coupled	D	DC Coupled				
DC-coupled Output (Voh)	С	rail-to rail LVCMOS				
DC-coupled Output (V _{oh}) or AC Swing	С	rail-to rail LVCMOS				
32.768k	Frequency Output					

Notes:

- For XTAL replacement applications that will keep the chipset oscillator enabled, configure the NanoDrive™ output for a swing similar to the XTAL, approximately 250mV
- Please consult with sales department for any other parameters or options.
- Oscillator specification subject to change without notice.



Absolute Maximum Limits						
Parameter	Test Condition	Value				
Continuous Power Supply Voltage Range (Vdd)		-0.5V to +3.63 V				
Short Duration Maximum Power Supply Voltage (Vdd)	≤30 minutes, over -40°C to +85°C	+4.0V				
Continuous Maximum Operating Temperature Range	Vdd = 1.5V - 3.63V	105°C				
Short Duration Maximum Operating Temperature Range	Vdd = 1.5V - 3.63V, ≤30 mins	125°C				
Human Body Model ESD Protection	HBM, JESD22-A114	3000 V				
Charge-Device Model (CDM) ESD Protection	JESD220C101	750 V				
Machine Model (MM) ESD Protection	TA = 25°C	300V				
Latch-up Tolerance	JESD78 Co	mpliant				
Mechanical Shock Resistance	Mil 883, Method 2002 10,000					
Mechanical Vibration Resistance	Mil 883, Method 2007	70 g				
2012 SMD Junction Temperature		150°C				
Storage Temperature		-65°C to +150°C				

	Pin Configuration						
Pin	Symbol	I/O	Functionality	SMD Package			
1	N/C	No Connect	No Connect. Will not respond to any input signal. When interfacing to an MCU's XTAL input pins, this pin is typically connected to the receiving IC's X Out pin. In this case, the IM890 will not be affected by the signal on this pin. If not interfacing to an XTAL oscillator, leave pin 1 floating (no connect).				
2	GND	Power Supply Ground	Connect to ground. All GND pins must be connected to power supply ground.				
3	CLK Out	Output	Oscillator clock output. When interfacing to an MCU's XTAL, the CLK Out is typically connected to the receiving IC's X IN pin. The IM890 oscillator output includes an internal driver. As a result, the output swing and operation is not dependent on capacitive loading. This makes the output much more flexible, layout independent, and robust under changing environmental and manufacturing conditions.	Z 4 TOP VIEW			
4	Vdd	Power Supply	Connect to power supply $1.5V \le Vdd \le 3.63V$ for operation over -40°C to +85°C temperature range. Under normal operating conditions, Vdd does not require external bypass/decoupling capacitor(s). Internal power supply filtering will reject more than ±150 mVpp with frequency components through 10 MHz.	3			

System Block Diagram



Figure 1.

QUALITY SYSTEM CERTIFIED = ISO 9001 =

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Pb Free RoHS IM890 Series



Description

The 1.2V to 3.63V operating supply voltage range makes it an ideal solution for mobile applications that incorporate a low-voltage, battery-back-up source such as a coin-cell or super-cap.

XTAL Footprint Compatibility (SMD Package)

The IM890 is a replacement to the 32 kHz XTAL in the 2.0 x 1.2 mm (2012) package. Unlike XTAL resonators, The ILSI silicon MEMS oscillators require a power supply (Vdd) and ground (GND) pin. Vdd and GND pins are conveniently placed between the two large XTAL pins. When using the ILSI Solder Pad Layout (SPL), the IM890 footprint is compatible with existing 32 kHz XTALs in the 2012 SMD package. Figure 2 shows the comparison between the quartz XTAL footprint and the ILSI footprint.



Figure 2 IM890 Footprint Compatibility with Quartz Crystal Footprint

Frequency Stability

The IM890 is factory calibrated (trimmed) to guarantee frequency stability to be less than 20 ppm at room temperature and less than 100 ppm over the full -40°C to +85°C temperature range. Unlike quartz crystals that have a classic tuning fork parabola temperature curve with a 25°C turnover point, the IM890 temperature coefficient is extremely flat across temperature. The device maintains less than 100 ppm frequency stability over the full operating temperature range when the operating voltage is between 1.5 and 3.63V.

Functionality is guaranteed over the 1.2V - 3.63V operating supply voltage range. However, frequency stability degrades below 1.5V and steadily degrades as it approaches the 1.2V minimum supply due to the internal regulator limitations. Between 1.2V and 1.5V, the frequency stability is 250 ppm max over temperature.

When measuring the IM890 output frequency with a frequency counter, it is important to make sure the counter's gate time is \geq 100ms. The slow frequency of a 32 kHz clock will give false readings with faster gate times.

The IM890 is an ultra-small 32 kHz oscillator. In addition to eliminating external output load capacitors common with standard XTALs, this device includes special power supply filtering and thus, eliminates the need for an external Vdd bypass-decoupling capacitor. This feature further simplifies the design and keeps the footprint as small as possible. Internal power supply filtering is designed to reject AC-noise greater than ±150 mVpp magnitude and beyond 10 MHz frequency component.

Output Voltage

The IM890 has two output voltage options One option is a standard LVCMOS output swing. The second option is the NanoDrive reduced swing output. Output swing is customer specific and programmed between 200 mV and 800 mV. For DC-coupled applications, output VOH and VoL are individually factory programmed to the customers' requirement. V_{OH} programming range is between 600 mV and 1.225V in 100 mV increments. Similarly, V_{OL} programming range is between 350 mV and 800 mV. For example; a PMIC or MCU is internally 1.8V logic compatible, and requires a 1.2V V_{IH} and a 0.6V V_{IL}.

Simply select IM890 NanoDrive factory programming code to be "D14" and the correct output thresholds will match the downstream PMIC or MCU input requirements. Interface logic will vary by manufacturer and we recommend that you review the input voltage requirements for the input interface.

For DC-biased NanoDrive output configuration, the minimum V_{OL} is limited to 350mV and the maximum allowable swing $(V_{OH}$ - $V_{OL})$ is 750mV. For example, 1.1V V_{OH} and 400mV V_{OL} is acceptable, but 1.2V V_{OH} and 400 mV V_{OL} is not acceptable.

When the output is interfacing to an XTAL input that is internally AC-coupled, the IM890 output can be factory programmed to match the input swing requirements. For example, if a PMIC or MCU input is internally AC-coupled and requires an 800mV swing, then simply choose the IM890 NanoDrive programming code "AA8" in the part number. It is important to note that the IM890 does not include internal ACcoupling capacitors. Please see the *Part Number Ordering* section of the datasheet for more information about the part number ordering scheme.

Power-up

The IM890 starts-up to a valid output frequency within 300 ms (150ms typ). To ensure the device starts-up within the specified limit, make sure the power-supply ramps-up in approximately 10 - 20 ms (to within 90% of Vdd). Start-up time is measured from the time Vdd reaches 1.5V. For applications that operate between 1.2V and 1.5V, the start-up time will be longer.

IM890 NanoDrive™

Figure 4 shows a typical IM890 output waveform (into a 10 pF load) when factory programmed for a 0.70V swing and DC bias (V_{OH}/V_{OL}) for 1.8V logic:

Power Supply Noise Immunity

<u>Example</u>:

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IM890 Series

Pb Free

- NanoDrive™ part number coding: D14.
- Example part number: IM890-ID14-32.768
- V_{OH} = 1.1V, V_{OL} = 0.4V (V_{_sw} = 0.70V)



Table 1 shows the supported NanoDrive ${}^{\rm T\!M}$ $V_{OH},$ V_{OL} factory programming options.

Table 1. Acceptable V_{OH}/V_{OL} NanoDrive™ Levels

V _{OL} /V _{OH}	1.225	1.100	1.000	0.900	0.800	0.700	0.600
0.800	D28	D18	D08				
0.700	D27	D17	D07	D97			
0.525	D26	D16	D06	D96	D86		
0.500	D25	D15	D05	D95	D85	D75	
0.400		D14	D04	D94	D84	D74	D64
0.350		D13	D03	D93	D83	D73	D63

Table 2 shows the supported AC coupled Swing levels. The "AC-coupled" terminology refers to the programming description for applications where the downstream chipset includes an internal AC-coupling capacitor, and therefore, only the output swing is important and V_{OH}/V_{OL} are not relevant.

Table 2. Acceptable AC-Coupled Swing Levels

Swing	0.800	0.700	0.600	0.500	0.400	0.300	0.250	0.200
Output Code	AA8	AA7	AA6	AA5	AA4	AA3	AA2	AA1

Example:

- NanoDrive part number coding: AA2. Example part number: IM890-4<u>AA2</u>-32.768
- Output voltage swing: 0.250V

The values listed in Tables 1 and -2 are nominal values at 25° C and will exhibit a tolerance of ± 55 mV across Vdd and -40°C to 85° C operating temperature range.

IM890 Full Swing LVCMOS Output

The IM890 can be factory programmed to generate fullswing LVCMOS levels. Figure 5 shows the typical LVCMOS waveform (Vdd = 1.8V) at room temperature into a 15 pF load.



Vdd = +1.8 V into 15pF Load

Example:

- LVCMOS output part number coding is always DCC
- Example part number: IM890-4DCC-32.768

Calculating Load Current

No Load Supply Current

When calculating no-load power for the IM890, the core and output driver components need to be added. Since the output voltage swing can be programmed for reduced swing between 250 mV and 800 mV, the output driver current is variable. Therefore, no-load operating supply current is broken into two sections; core and output driver. The equation is as follows:

Total Supply Current (no load) = I_{dd} Core + (65nA/V)(Vout_{pp})

Example 1: Full-swing LVCMOS

- Vdd = 1.8V
- Idd Core = 900nA (typ)
- Vout_{pp} = 1.8V (LVCMOS)

Supply Current = 900nA + (65nA/V)(1.8V) = 1017nA

Example 2: NanoDrive™ Reduced Swing

- Vdd = 1.8V
- Idd Core = 900nA (typ)
- Vout_{pp} (Programmable) = V_{OH} V_{OL} = 1.1V 0.6V = 500 mV

Supply Current = 900nA + (65nA/V)(0.5V) = 932nA

Total Supply Current with Load

To calculate the total supply current, including the load, follow the equation listed below. Note the 30% reduction in power with NanoDrive™.

Total Current = Idd Core + Idd Output Driver (65nA/V*Vout_{pp}) + Load Current (C*V*F

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Example 1: Full-swing LVCMOS

- Vdd = 1.8V
- Idd Core = 900nA
- Load Capacitance = 10pF
- Idd Output Driver: (65nA/V)(1.8V) = 117nA
- Load Current: (10pF)(1.8V)(32.768kHz) = 590nA
- Total Current = 900nA+117nA+590nA = 1.6µA

<u>Example 2:</u> NanoDrive™ Reduced Swing

- Vdd = 1.8V
- Idd Core = 900nA
- Load Capacitance = 10pF
- Vout_{pp} (Programmable): $V_{OH} V_{OL} = 1.1V 0.6V = 500mV$
- Idd Output Driver: (65nA/V)(0.5V) = 33nA
- Load Current: (10pF)(0.5V)(32.768kHz) = 164nA
- Total Current = 900nA + 33nA + 164nA = 1.1µA







Environmental Specifications:

Environmental Compliance					
Parameter	Condition/Test Method				
Mechanical Shock	MIL-STD-883F, Method 2002				
Mechanical Vibration	MIL-STD-883F, Method 2007				
Temperature Cycle	JESD22, Method A104				
Solderability	MIL-STD-883F, Method 2003				
Moisture Sensitivity Level	MSL Level 1 at +260°C				



Units are backward compatible with +240°C reflow processes

Ts max to T _L (Ramp-up Rate)	3°C / second max
Preheat Temperature min (Ts min) Temperature typ (Ts typ) Temperature max (Ts max) Time (Ts)	150°C 175°C 200°C 60 to180 seconds
Ramp-up Tate (T _L to Tp	3°C / second max
Time Maintained Above Temperature (T_L) Time (T_L)	217°C 60 to 150 seconds
Peak Temperature (Tp)	260°C max for seconds
Time within 5°C to Peak Temperature (Tp)	20 to 40 seconds
Ramp-down Rate	6°C / second max
Tune 25°C to Peak Temperature	8 minute max
Moisture Sensitivity Level (MSL)	Level 1

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Typical Operating Curves (T_A = 25°C, Vdd = 1.8V, unless otherwise stated)



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Typical Operating Curves (cont.)









NanoDrive[™] Output Waveform V_{oh} = 1.1V, V_{ol} = 0.4V; IM890-ID14-32.768

LVCMOS Output Waveform Vswing = 1.8V: IM890-IDCC-32.768

Tape and Reel Dimensions



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Mechanical Details:



Marking

Line 1 = XXXXX (Lot code) Dot to denote Pin 1 location

Notes:`

- All dimensions are in mm.
- Do not scale drawings.
- QUALITY SYSTEM CERTIFIED = ISO 9001 =

Package Information

Leadframe: C194

Plating: NiPdAu

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